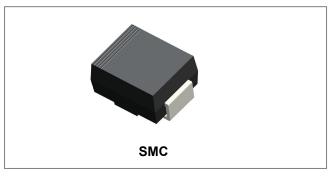


# RS3A-RS3M

Technical Data Data Sheet N1813, Rev.A



# RS3A-RS3M SURFACE MOUNT SUPER FAST RECTIFIER



### Features

- Glass Passivated chip junction
- Built-in strain relief
- Fast switching speed for high efficiency
- High temperature soldering guaranteed: 250°C/10 second at terminals
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### **Mechanical Data**

- Case: SMC molded plastic
- Epoxy: UL 94V-0 rate flame retardant
- Lead: Solder plated, solderable per MIL-STD-202E method208C
- Polarity: Color band denotes cathode end
- Weight: 0.21 grams

## Maximum Ratings and Electrical Characteristics @TA=25°C unless otherwise specified

Type Number	Symbol	RS3A	RS3B	RS3D	RS3G	RS3J	RS3K	RS3M	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>DC</sub>	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	V <sub>RMS</sub>	35	70	140	280	420	560	700	V
Average forward rectified output current @TL= 100°C	lo				3.0				А
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I <sub>FSM</sub>	100				А			
Forward Voltage @I <sub>F</sub> =3.0A	VF				1.3				V
Peak Reverse Current@TA = 25°CAt Rated DC Blocking Voltage@TA = 125°C	I <sub>RM</sub>	та 10 250			μA				
Maximum Reverse Recovery Time (Note 1)	Trr		1:	50		250	50	00	ns
Typical Junction Capacitance (Note 2)	CJ	60				pF			
Typical Thermal Resistance Junction to Ambient (Note 3)	R <sub>0JA</sub> R <sub>0JL</sub>	50 15				°C/W			
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150					°C		

Note: 1. Measured with  $I_F$ =0.5A,  $I_R$ =1.0A,  $I_m$ =0.25A,

2. Measured at 1.0 MHZ and applied reverse voltage of 4.0 VDC

3. Thermal resistance from Junction to ambient and from junction to lead mounted on PCB with  $0.3 \times 0.3$ " (8.0  $\times$  8.0mm) copper pad areas

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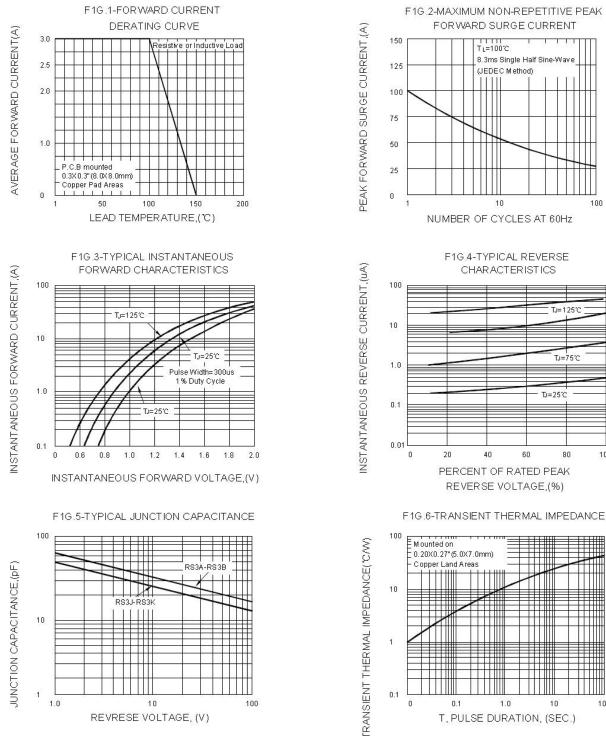
## **Circuit Diagram**





#### **Technical Data** Data Sheet N1813, Rev.A

## **Ratings and Characteristics Curves**



10

RS3A-RS3M



100

TJ=125%

TJ=75°C

80

100

100

TJ=25°C

60

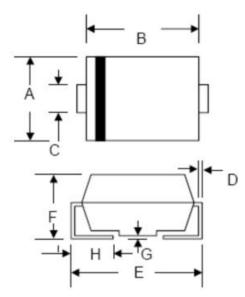
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# RS3A-RS3M

Technical Data Data Sheet N1813, Rev.A

# Mechanical Dimensions SMC



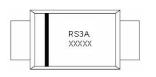
SYMBOL	Millir	neters	Inches		
STNIBOL	Min.	Max.	Min.	Max.	
А	5.59	6.22	0.220	0.245	
В	6.60	7.11	0.260	0.280	
С	2.90	3.20	0.114	0.126	
D	0.152	0.305	0.006	0.012	
E	7.75	8.13	0.305	0.320	
F	2.00	2.62	0.079	0.103	
G	-	0.203	-	0.008	
н	0.76	1.52	0.030	0.060	

## **Ordering Information**

Device	Package	Shipping
RS3A-RS3M	SMC (Pb-Free)	3000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

# Marking Diagram



Where XXXXX is YYWWL

RS3A

YY WW

L

= Type Number

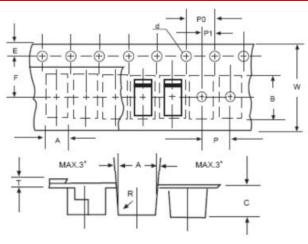
= Year

= Week

= Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

# **Carrier Tape Specification SMC**



SYMBOL	Millimeters			
	Min.	Max.		
A	5.90	6.10		
В	8.20	8.40		
С	2.40	2.60		
d	1.40	1.60		
E	1.40	1.60		
F	7.60	7.70		
Р	7.90	8.10		
P0	3.90	4.10		
P1	3.90	4.10		
Т	-	0.600		
W	15.80	16.20		

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